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Substitute for form 1449B/PTO		Complete if Known			
		Application Number	10/708,223		
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)		Filing Date	02/17/2004		
		First Named Inventor	Ming-Dou Ker		
		Group Art Unit			
		Examiner Name			
Sheet	1	of	1	Attorney Docket Number	SISP0008USA

OTHER PRIOR ART -- NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No.¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T²
	1	H. NEUTEBOOM, B.M. J. KUP, M. JANSSENS; A DSP-based hearing instrument IC; IEEE Journal of Solid-State Circuits, Nov. 1997; page 1790 - page 1806; VOL. 32.	
	2	H. BANBA, H. SHIGA, A. UMEZAWA, T. MIYABA, T. TANZAWA, S. ATSUMI, K. SAKUI; A CMOS bandgap reference circuit with sub 1-V operation; IEEE Journal of Solid-State Circuits; May 1999; page 670 - page 674; VOL. 34	
	3	G. GIUSTOLISI; A Low-Voltage Low-Power Voltage Reference Based on Subthreshold MOSFETs; IEEE Journal of Solid-State Circuits; Jan. 2003, page 151 - page 154; VOL.38, No.1	
	4	P. MALCOVATI, F. MALOBERTI, M. PRUZZI, C. FIOCCCHI; Curvature compensated BiCMOS bandgap with 1-V supply voltage; IEEE Journal of Solid-State Circuits; July 2001; page 52 - page 55; VOL.36, No.7	
	5	YUEMING JIANG, EDWARD K.F. LEE; A 1.2 V bandgap reference based on transimpedance amplifier; ISCAS 2000-IEEE international symposium on Circuits and Systems; May 23-31, 2000; page 261 - page 264	
	6	SHU-YUAN CHIN, CHUNG-YU WU; A New Type of Curvature-Compensated CMOS Bandgap Voltage Reference; VLSITSA; 1991; page 398 - page 402	
	7	KA NANG LEUNG, IEEE, PHILIP K. T. MOK; A Sub-1-V 15-ppm/C CMOS Bandgap Voltage Reference without Requiring Low Threshold Voltage Device; IEEE Journal of Solid-State Circuits; April 2002; page 526 - page 530; VOL.37, No.4	

Examiner Signature		Date Considered	Dec 04
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